

PHOTON IS OUR BUSINESS

# **Micro-spectrometer**

NEW

C12666MA

# Finger-tip size, ultra-compact spectrometer head integrating MEMS and image sensor technologies

The C12666MA is an ultra-compact (Finger-tip size) spectrometer head developed based on our MEMS and image sensor technologies. The adoption of a newly designed optical system has achieved a remarkably small size, less than half the volume of the previous mini-spectrometer MS series (C10988MA-01). In addition, the employment of hermetic packaging has improved humidity resistance.

This product is suitable for integration into a variety of devices, such as integration into printers and hand-held color monitoring devices that require color management. It is also suitable for applications that collaborate with portable devices, such as smartphones and tablets.

#### Features

Finger-tip size: 20.1 × 12.5 × 10.1 mm

- Weight: 5 g
- Spectral response range: 340 to 780 nm
- Spectral resolution: 15 nm max.
- Hermetic package: High reliability against humidity
- Installation into mobile measurement equipment
- Wavelength conversion factor\*1 is listed on final inspection sheet

#### Applications

- Color monitoring for printers and printing machines
- Testers for lights and LEDs
- Color adjustment of various large size displays
- Water quality control monitors and other environment measuring instruments
- Measuring instruments that use portable devices such as smartphones and tablets
- \*1: A conversion factor for converting the image sensor pixel number into a wavelength. A calculation factor for converting the A/D converted count into the input light level is not provided.

# Optical characteristics

Parameter	Value	Unit
Spectral response range	340 to 780	nm
Spectral resolution (FWHM)	15 max.	nm
Wavelength reproducibility*2	-0.5 to +0.5	nm
Wavelength temperature dependence	-0.1 to +0.1	nm/°C
Spectral stray light*3	-25	dB

\*2: Measured under constant light input conditions

\*3: Spectral stray light =  $10 \times \log (TI/Th)$ 

Th: count measured when light at a certain wavelength is input

TI: count measured at a wavelength 40 nm longer or shorter than the input light wavelength

#### Electrical characteristics

Parameter	Min.	Тур.	Max.	Unit
Supply voltage	4.75	5	5.25	V
Power consumption	-	30	-	mW
Video rate	0.25	-	200	kHz
Output impedance	-	150 *4	-	Ω

\*4: An increase in the current consumption at the video output terminal also increases the chip temperature and so causes the dark current to rise. To avoid this, connect a buffer amplifier for impedance conversion to the video output terminal so that the current flow is minimized. As the buffer amplifier, use a JFET or CMOS input operational amplifier of optical input impedance.

# Structure

Parameter	Specification	Unit
Dimensions (W $\times$ D $\times$ H)	20.1 × 12.5 × 10.1	mm
Weight	5	g
Slit <sup>*5</sup> (H × V)	50 × 750	μm
NA* <sup>6</sup>	0.22	-
Image sensor $(H \times V)$	CMOS linear image sensor with a slit	-
Number of pixels	256	pixels
Pixel size (H $\times$ V)	12.5 × 1000	μm

\*5: Entrance slit aperture size

\*6: Numeric aperture (solid angle)

# Absolute maximum ratings

Parameter	Value	Unit
Operating temperature*7	+5 to +40	°C
Storage temperature*7	-20 to +70	°C

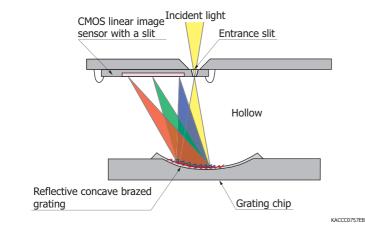
\*7: No condensation

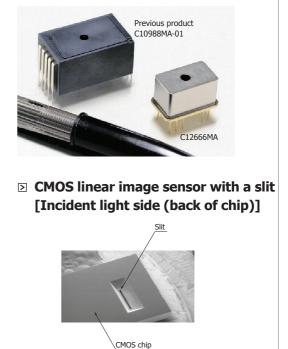
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

#### Optical component layout

Besides a CMOS image sensor chip integrated with an optical slit by etching technology, the C12666MA employs a reflective concave brazed grating formed by nanoimprint. In addition, the glass used in the light path of the previous C10988MA-01 is not used in the C12666MA, making it extremely compact.

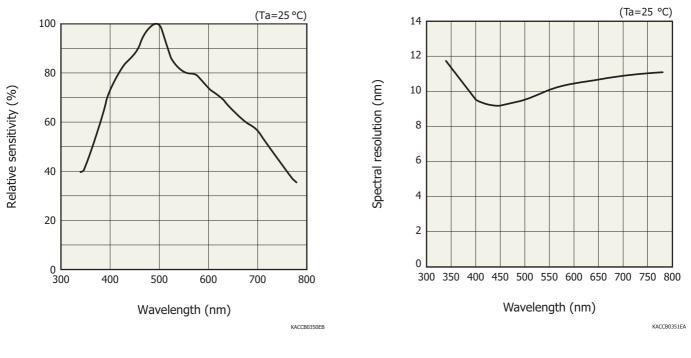
#### ▷ Structure







# C12666MA

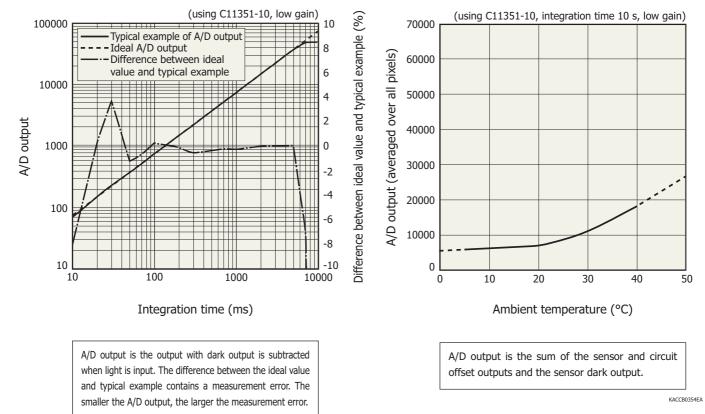


# Spectral response (typical example)

Linearity (typical example)

# Dark output vs. ambient temperature (typical example)

Spectral resolution vs. wavelength (typical example)

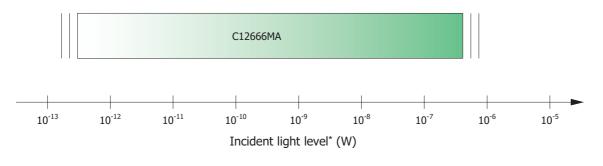


KACCB0352EA

PHOTON IS OUR BUSINESS

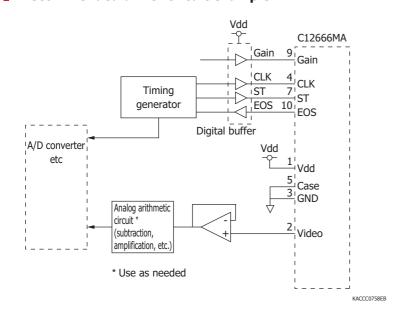
3

#### Measurable incident light level



\* Input spot diameter: 800  $\mu$ m ( $\lambda$ =550 nm)

Recommended driver circuit example



# Precautions

• The C12666MA is electrically conductive, so be careful when designing the circuit to avoid short circuit caused by contact with a circuit pattern.

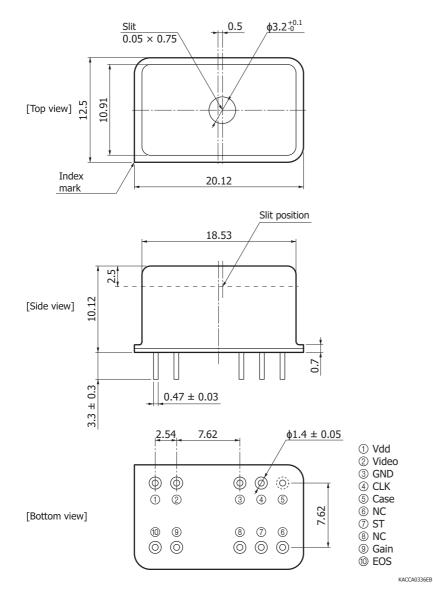
 $\cdot$  If external force is repeatedly applied to the lead pins, this may damage the lead pins.

 $\cdot$  To prevent damage due to soldering, be careful of the soldering temperature and time.

As a general guide, finish soldering within 3.5 seconds at 350 °C or less when soldering by hand, or within 10 seconds at 260 °C or less when using a solder bath.



KACCB354EA



# Dimensional outline (unit: mm, tolerance unless otherwise noted: ±0.2)

# Pin connections

Make electrical connections to an external circuit using leads.

Pin no.	Symbol	Name	I/O	Description
1	Vdd	Supply voltage	I	Image sensor power supply: 5 V
2	Video	Video output	0	Video output signal
3	GND	Ground	-	Sensor ground
4	CLK	Clock pulse	I	Sensor scan sync signal
5	Case	Case	-	Case connection terminal
6	NC		-	No connection
7	ST	Start pulse	I	Start pulse
8	NC		-	No connection
9	Gain	Gain	I	Image sensor: Gain setting
10	EOS	End of scan	0	Sensor scan end signal

Note: Pin no. 9 is pulled up internally to Vdd via 10 k $\Omega$ 

Do not pull-up or pull-down the gain setting using an external circuit. For low gain, leave the pin open or connect to Vdd. For high gain, connect to GND.



#### Internal CMOS image sensor specifications

#### Recommended terminal voltage

Parameter		Symbol	Min.	Тур.	Max.	Unit
Supply voltage		Vdd	4.75	5	5.25	V
Gain selection terminal	High gain	Gain	0	-	0.4	V
voltage	Low gain	Gain	Vdd - 0.25	Vdd	Vdd + 0.25	V
Clock pulse voltage	High level	V(CLK)	Vdd - 0.25	Vdd	Vdd + 0.25	V
	Low level		0	-	0.4	V
Start pulse voltage	High level	V(ST)	Vdd - 0.25	Vdd	Vdd + 0.25	V
	Low level	V(ST)	0	-	0.4	V

# Electrical characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit
Clock pulse frequency*8		f(CLK)	1	-	800	kHz
Power concumption	High gain	р	-	-	60	mW
Power consumption	Low gain		-	-	60	11100

\*8: Ta=25 °C, Vdd=5 V, V(CLK)=V(ST)=5

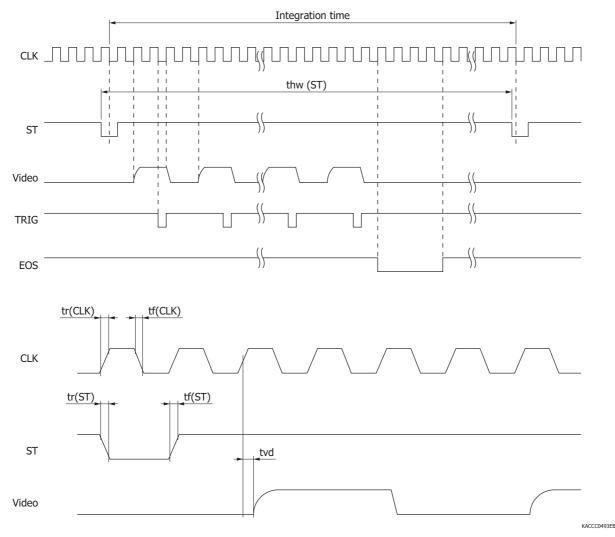
# Electrical and optical characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit
Dark current	High gain	TD	-	0.02	0.08	
Dark current	Low gain	ID	-	0.02	0.08	рА
Output offset voltage	High gain	Vo	0.15	0.35	0.55	V
	Low gain		0.15	0.35	0.55	v
Charge amplifier feedback	High gain	Cf	-	1.4	-	pF
capacitance*9	Low gain		-	4.8	-	
Saturation output voltage*10	High gain	Veat	2.3	2.8	3.3	V
Saturation output voltage 10	Low gain	Vsat	1.4	1.7	2.0	V
Des deut reise	High gain	Nr	-	0.3	0.5	mV rms
Readout noise	Low gain		-	0.2	0.4	

\*9: Gain=5 V (low gain), Vg=0 V (high gain) \*10: Voltage difference relative to Vo



# Timing chart



Daramatar	Cumbol	Min	Tur	Max	Linit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Start pulse high period	thw(ST)	1030/f(CLK)	-	-	S
Start pulse rise/fall times	tr(ST), tf(ST)	0	20	30	ns
Clock pulse duty ratio	-	45	50	55	%
Clock pulse rise/fall times	tr(CLK), tf(CLK)	0	20	30	ns
Video delay time	tvd	-	20	-	ns

Note: The clock pulse should be set from high to low just once when the start pulse is low. The internal shift register starts operating at this timing.

The integration time is determined by the start pulse intervals. However, since the charge integration of each pixel is carried out between the signal readout of that pixel and the next signal readout of the same pixel, the start time of charge integration differs depending on each pixel. In addition, the next start pulse cannot be input until signal readout from all pixels is completed. Video output is 1/4 of the clock pulse frequency.



#### Micro-spectrometer evaluation circuit C11351-10 (sold separately)

The C11351-10 is a circuit board designed to simply evaluate the characteristics of the micro-spectrometer. The characteristics of the micro-spectrometer can be evaluated using the evaluation software by connecting the micro-spectrometer to a PC with a USB cable A9160 (AB type, sold separately)<sup>\*11</sup>.

#### Features

- Initial evaluation circuit for micro-spectrometer\*12
- Wavelength conversion factors of the micro-spectrometer can be input from a PC.\*13
- High A/D resolution (16-bit)
- USB powered
- \*11: Compatible OS:



- Microsoft<sup>®</sup> Windows<sup>®</sup> 7 Professional SP1 (32-bit), Microsoft<sup>®</sup> Windows<sup>®</sup> 7 Professional SP1 (64-bit) Microsoft and Windows are registered trademarks of Microsoft Corporation in the United States and/or other countries.
- \*12: The C11351-10 is a modified version of the C11351 evaluation circuit for the previous mini-spectrometer MS series (C10988MA-01, C11708MA). Only the sensor board has been modified. If you already have the C11351, you only have to purchase the C11351-03 (the sensor board for micro-spectrometers) to evaluate C12666MA micro-spectrometers.
- \*13: A typical wavelength conversion factor is entered at the time of shipment of the C11351-10. To measure a spectrum with higher wavelength accuracy, it is necessary to input the wavelength conversion factor listed in the final inspection sheet that comes with each micro-spectrometer.

Note: Since the C11351-10 is an evaluation circuit for the micro-spectrometer, the DLL function specifications are not available to users.

#### Electrical characteristics

Parameter	Specification	Unit
Interface	USB 2.0	-
A/D conversion	16	bit
Clock pulse frequency	800	kHz
Video rate	200	kHz
Integration time	5 to 10000	ms

#### Structure

Parameter		Specification	Unit
Applicable spectr	ometer	C12666MA	-
Dimensions Control board		80 × 60	mm
DIMENSIONS	Sensor board	30 × 44	mm

#### Absolute maximum ratings

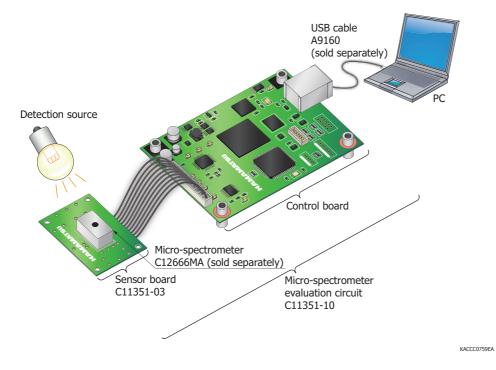
Parameter	Value	Unit
Operating temperature*14	+5 to +40	°C
Storage temperature*14	-20 to +70	°C

\*14: No condensation

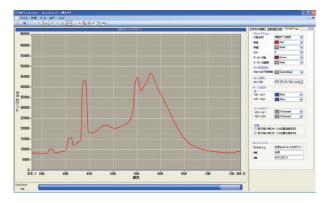
Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.



# Connection example



# Evaluation software display example





# Mini-spectrometer/micro-spectrometer lineup

Turne		- 								-	Spe	ctra	l res	noq	ıse	rar	nae	(nr	n)						Spectral resolution	Turner				
Type no.		Туре	200	) 4	00	60	0 8	800	) 10											2200	24	400	26	500	max. (nm)	Image sensor				
C10082CA		TM-UV/VIS-CCD High sensitivity																							6	Back-thinned typ				
C10082CAH	Mini-spectrometer TM series	TM-UV/VIS-CCD High resolution	2	20	)0 to	o 80	00																		1*	CCD image sense				
C10082MD		TM-UV/VIS-MOS Wide dynamic range																							6	CMOS linear image sensor				
C10083CA		TM-VIS/NIR-CCD High sensitivity																							8 (λ=320 to 900 nm)	Back-thinned typ				
C10083CAH		TM-VIS/NIR-CCD High resolution			22		- 1/																		1* (λ=320 to 900 nm)	CCD image sens				
C10083MD		TM-VIS/NIR-MOS Wide dynamic range			∡د ا	20 1	:0 1(		J																8	CMOS linear image sensor				
C11697MA		TM-VIS/NIR-MOS-II Trigger-compatible																							8	CMOS image sens with amp array				
C9404CA	meter	TG-UV-CCD High sensitivity	200	0 to 100	1																				3	Back-thinned typ				
C9404CAH		TG-UV-CCD High resolution		0 10 401	1																				T.,	CCD image sens				
C9405CB	spectrometer ries	TG-SWNIR-CCD-II IR-enhanced				5	00 t	to	1100	)															5 (λ=550 to 900 nm)	IR-enhanced back-thinned typ CCD image sense				
C11713CA	Mini- spec TG series	TG-RAMAN-I High resolution					500	) to	o 60	0															0.3*	Back-thinned ty				
C11714CA		TG-RAMAN-II High resolution								790	) to	920	)												0.3*	CCD image sens				
C11482GA	ter	TG2-NIR Non-cooled type									000		170												7	InGaAs linear				
C9913GC	Mini-spectrometer TG series	TG-cooled NIR-I Low noise (cooled type)									900		1/0												7					
C9914GB	ii-spec series	TG-cooled NIR-II Low noise (cooled type)											1	100	to	22	00								8	image sensor				
C11118GA		TG-cooled NIR-III Low noise (cooled type)				900 to 2550 20										20														
C11007MA	trometer	RC-VIS-MOS Spectrometer module			340 <sup>-</sup>	to 7	780	]																	9	CMOS linear image sensor				
C11008MA	Mini- spectrometer RC series	RC-SWNIR-MOS Spectrometer module					640	) tc	0 105	0															8	IR-enhanced CMOS linear image sensor				
Тур.																														
Installation into mot	oile m	easurement equi	omer	t														,					_		Spectral resolution					
Type no.		Туре	200	4	00	60	3 0	300	) 10									(nn 200		2200	24	100	26	600	max. (nm)	Image senso				
C11009MA	trometer	RC-VIS-MOS Spectrometer head			340	to 🛛	780																		9	CMOS linear image sensor				
C11010MA	Mini- spectrometer RC series	RC-SWNIR-MOS Spectrometer head					640	) to	0 105	50															8	IR-enhanced CMOS linear image sensor				
Installation into mot	oile m	easurement equi	omer	it (u	ltra-	con	npac	t)																						
Type no.		Туре	200	) 4	00	60	0 8	800	) 10	ع 000	Spe 12	ctra 00	l res 1400	spor ) 16	nse 500	rar 18	nge 00	(nr 200	n) 0 2	2200	) 24	400	26	500	Spectral resolution max. (nm)	Image senso				
C10988MA-01	trometer	MS-VIS-MOS Spectrometer head			340 1															Τ					14	CMOS linear				
C11708MA	Mini- spectrometer MS series	MS-SWNIR-MOS Spectrometer head					640	) tc	0 105	0															20	image sensor				
C12666MA	Micro- spectrometer	Spectrometer head			340	to	780																		15	CMOS linear image sensor				



# Related information

www.hamamatsu.com/sp/ssd/doc en.html

- Precautions
  - Notice

Technical information

· Mini-spectrometer / Technical information

Information described in this material is current as of July, 2014.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

Type numbers of products listed in the delivery specification sheets or supplied as samples may have a suffix "(X)" which means preliminary specifications or a suffix "(Z)" which means developmental specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.



#### www.hamamatsu.com

#### HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184

U.S.A.: Hamamatsu Corporation: 360 Foothill Road, Bridgewater, N.J. 08807, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-1218 Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 8152-375-0, Fax: (49) 8152-265-8

Germany: Hamamatsu Photonics Deutschiand GmbH: Arzbergerstr. 10, D-82/211 Herrsching am Ammersee, Germany, Telephone: (49) 815/2-3/5-0, Fax: (49) 815/2-265-8 France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, Q1882, Massy, Catex, France, Telephone: 33-(1) 69 53 71 10, 69 53 71 10, 69 53 71 10, 69 53 71 10, 69 53 71 10, 69 53 71 10, 69 53 71 10, 69 53 71 10, 69 53 71 10, 70 Fax: 33-(1) 69 53 71 Fax: 70 Fax: 7